

### FEATURES

- 1). Hermetic metal case with ceramic insulator
- 2). Threaded stud ISO M24 × 1.5 or UNF 3/4-16
- 3). High  $i^2t$  and  $I_{TSM}$  values for easy fusing
- 4). International standard case

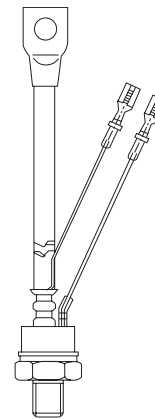
### MAJOR RATINGS AND CHARACTERISTICS

$V_{RSM}$	$V_{RRM}, V_{DRM}$	$I_{TRMS}=450A$ (maximum value for continuous operation) $I_{TAV}=250A$ (sin. 180° ; $T_c=85^\circ C$ )
V	V	
500	400	SKT 300/04D
900	800	SKT 300/08D <sup>1)*</sup>
2400	1200	SKT 300/12E <sup>1)*</sup>
1500	1400	SKT 300/14E <sup>1)*</sup>
1700	1600	SKT 300/16E <sup>1)*</sup>

1)\* Available with UNF thread 3/4-16 UNF2A, e.g. SKT 300/08D UNF

### TYPICAL APPLICATIONS

- 1). DC motor control (e.g. for machine tools)
- 2). Controlled rectifiers (e.g. for battery charging)
- 3). AC controllers (e.g. for temperature control)
- 4). Recommended snubber network:  
e.g. for  $V_{VRMS} \leq 400V$ :  $R=33\Omega/32W$ ,  $C=0.47\mu F$



### ELECTRICAL SPECIFICATIONS

Symbol	Conditions	Values	V
$I_{TAV}$	sin. 180; $T_c=100(85)^\circ C$	257(351)	A
$I_D$	K0.55; $T_a=45^\circ C$ ; B2/B6	250/360	A
	K0.55F; $T_a=35^\circ C$ ; B2/B6	570/800	A
$I_{RSM}$	K0.55; $T_a=45^\circ C$ ; W1C	280	A
$I_{TSM}$	$T_{vj}=25^\circ C$ ; 10ms	11000	A
	$T_{vj}=130^\circ C$ ; 10ms	10000	A
$I^2t$	$T_{vj}=25^\circ C$ ; 8,35 ... 10ms	600000	A <sub>2</sub> S
	$T_{vj}=130^\circ C$ ; 8,35 ... 10ms	500000	A <sub>2</sub> S
$V_T$	$T_{vj}=25^\circ C$ ; $I_T=800A$	max. 1.45	V
$V_{T(TO)}$	$T_{vj}=130^\circ C$	max. 0.9	V
$r_T$	$T_{vj}=130^\circ C$	max. 0.5	m $\Omega$
$I_{DD}; I_{RD}$	$T_{vj}=130^\circ C$ ; $V_{RD}=V_{RRM}$ ; $V_{DD}=V_{DRM}$	max. 50	mA
$t_{gd}$	$T_{vj}=25^\circ C$ ; $I_G=1A$ ; $di_G/dt=1A/\mu s$	1	$\mu s$
$t_{gr}$	$V_D=0.67 * V_{DRM}$	2	$\mu s$
$(di/dt)_{cr}$	$T_{vj}=130^\circ C$	max. 100	A/ $\mu s$
$(dv/dt)_{cr}$	$T_{vj}=130^\circ C$ ; SKT ... D/SKT ... E	max. 500/1000	V/ $\mu s$
$t_q$	$T_{vj}=130^\circ C$	50...150	$\mu s$
$I_H$	$T_{vj}=25^\circ C$ ; typ./max.	150/250	mA
$I_L$	$T_{vj}=25^\circ C$ ; $R_G=33\Omega$ ; typ./max.	300/600	mA

Symbol	Conditions	Values	V
$V_{GT}$	$T_{vj}=25^{\circ}\text{C}$ ; d.c.	min.3	V
$I_{GT}$	$T_{vj}=25^{\circ}\text{C}$ ; d.c.	min.200	mA
$V_{GD}$	$T_{vj}=130^{\circ}\text{C}$ ; d.c.	max.0.25	V
$I_{GD}$	$T_{vj}=130^{\circ}\text{C}$ ; d.c.	max.10	mA
$R_{th(j-c)}$	cont.	0.09	K/W
$R_{th(j-c)}$	sin.180	0.096	K/W
$R_{th(j-c)}$	rec.120	0.101	K/W
$R_{th(c-s)}$		0.015	K/W
$T_{vj}$		-40 ... +130	$^{\circ}\text{C}$
$T_{stg}$		-40 ... +150	$^{\circ}\text{C}$
$V_{isol}$		-	V~
$M_s$	mounting force	60(UNF: 30)	Nm
a		5*9.81	$\text{m/s}^2$
m	approx.	490	g
Case		B7	

PERFORMANCE CURVES FIGURE

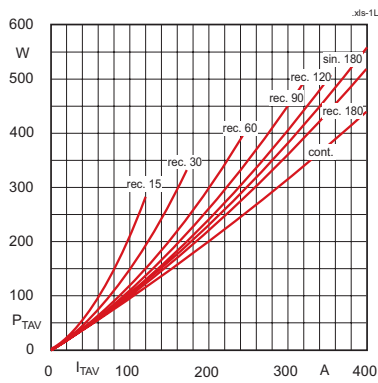


Fig. 1L Power dissipation vs. on-state current

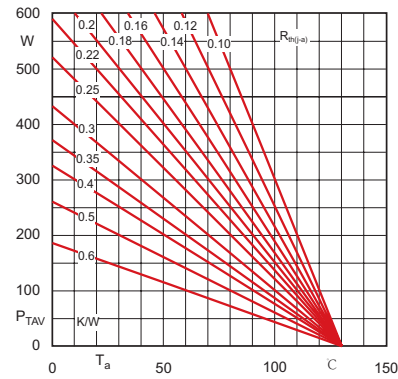


Fig. 1R Power dissipation vs. ambient temperature

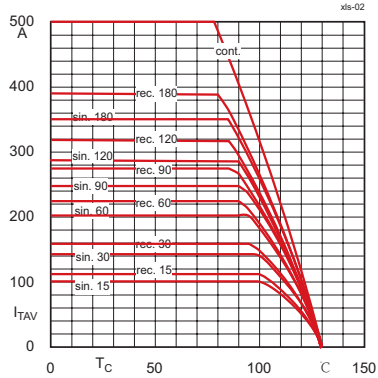


Fig. 2 Rated on-state current vs. case temperature

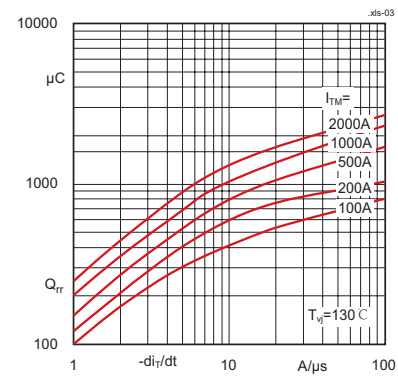


Fig. 3 Recovered charge vs. current decrease

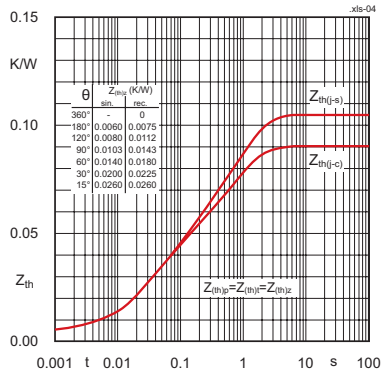


Fig. 4 Transient thermal impedance vs. time

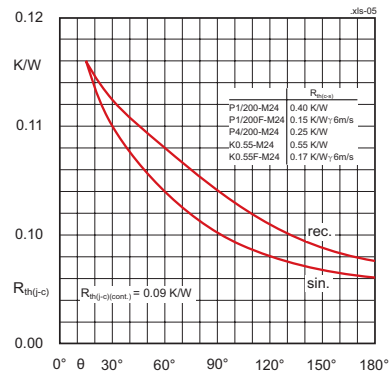


Fig. 5 Thermal resistance vs. conduction angle

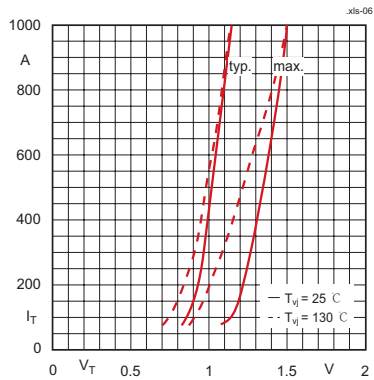


Fig. 6 On-state characteristics

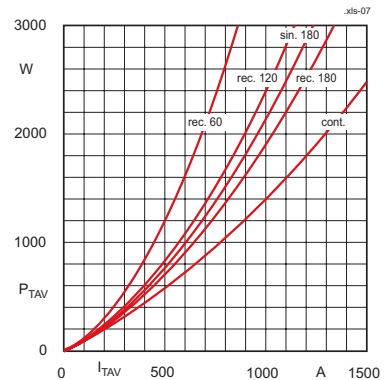


Fig. 7 Power dissipation vs. on-state current

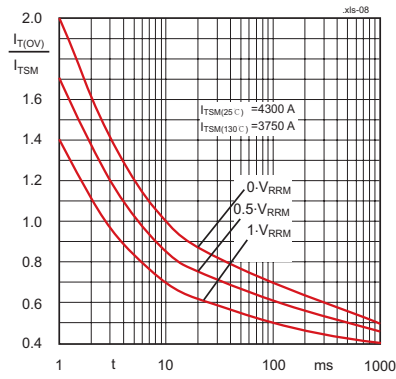


Fig. 8 Surge overload current vs. time

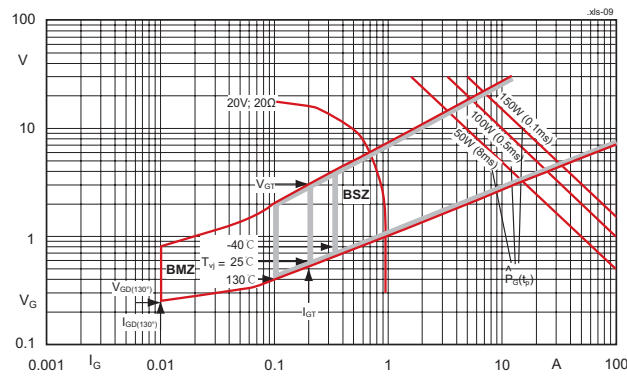
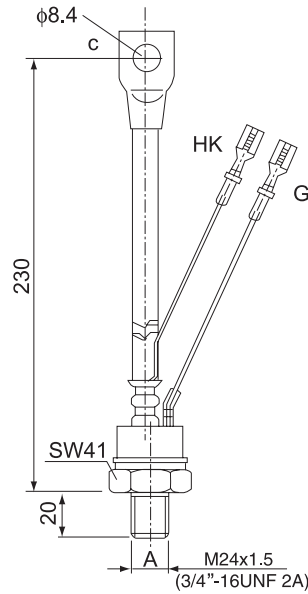


Fig. 9 Gate trigger characteristics

**OUTLINE**



**SKT10**

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